

Subscribe to NEWS FLASH

Subscribe now to keep up to date with breaking news from the light source community.

RSS

either of its components. For most eutectic alloys, the difference between the melting point of the alloy and those of its pure components is about 100 degrees Celsius; the gold-silicon eutectic alloy melts about 1,000 °C lower than either of its components, at 360 °C (680 °F). But that's not the only unusual thing about the gold-silicon eutectic alloy. In a crystalline solid, atoms are arranged in an

eutectic alloy. In a crystalline solid, atoms are arranged in an orderly, periodic fashion, and in a liquid, arrangements of atoms are disordered. It's been known for about 10 years that many metallic liquids show two or three distinct atomic layers near the surface, and usually there is no crystalline-like order within these layers. However, Shpyrko and his colleagues found that the gold-silicon eutectic alloy has seven or eight layers near its surface. In trying to understand this unexpected development, they found also that the top-most surface layer includes a crystal-like structure, similar to that normally found only in solid substances.



Image 1. This image represents periodically ordered gold (yellow) and silicon (blue) atoms within the surface-frozen monolayer of liquid gold-silicon eutectic alloy (Courtesy: Argonne National Laboratory)

Understanding characteristics of novel surface phases like this surface-frozen monolayer is important for the growing realm of nanotechnology, in which the basic unit of measurement is a billionth of a meter.

"By the time you reduce the size of an object or device down to one nanometer, practically everything is surfaces and interfaces," Shpyrko said. "We need to understand what the new laws of physics and chemistry that govern the surface structures are."

Gold and silicon are especially important to understand because they are used in computer technology. Gold is an oxide-resistant "noble" metal that is easily shaped into tiny computer chip interconnects, and silicon is the principal component of most semiconductor devices.

"If you think about it, you have gold and silicon in contact with each other in about every electronic device," Shpyrko said.

Shpyrko began the research as a doctoral student at Harvard University and finished it at Argonne. He used Argonne's <u>Advanced Photon Source</u>, which provides the most brilliant X-ray beams available in the Western Hemisphere, to perform several tests on the material: X-ray specular reflectivity, which provides information about atomic structure normal to the surface; X-ray grazing incidence diffraction, which provides information about in-plane structure; X-ray diffuse scattering, which provides information about waves and other dynamics at the surface; and X-ray crystal truncation rod, which measures thickness and structure of the crystalline surface layer.

Co-authors on the *Science* article were Reinhard Streitel, Venkatachalapathy S.K. Balagurusamy, Alexei Y. Grigoriev and Prof. Peter S. Pershan of <u>Harvard University</u>; Prof. Moshe Deutsch of <u>Bar-Ilan University</u> in

Israel; Benjamin M. Ocko of <u>Brookhaven National Laboratory</u>; and Mati Meron and Binhua Lin of <u>The</u> <u>University of Chicago</u>.

This work was supported by the Department of Energy, through the <u>Office of Science</u> Office of <u>Basic</u> <u>Energy Sciences</u>, and by the <u>U.S.-Israel Binational Science Foundation</u>, Jerusalem. Measurements at Brookhaven were also supported by the Office of Basic Energy Sciences.

###

The nation's first national laboratory, Argonne National Laboratory conducts basic and applied scientific research across a wide spectrum of disciplines, ranging from high-energy physics to climatology and biotechnology. Since 1990, Argonne has worked with more than 600 companies and numerous federal agencies and other organizations to help advance America's scientific leadership and prepare the nation for the future. Argonne is managed by the <u>University of Chicago</u> for the <u>U.S. Department of Energy</u>'s <u>Office of Science</u>.

[Note: Published in Science, <u>7 July 2006: Vol. 313. no. 5783, pp. 77 - 80, DOI:</u> <u>10.1126/science.1128314</u>; Oleg G. Shpyrko, Reinhard Streitel, Venkatachalapathy S. K. Balagurusamy, Alexei Y. Grigoriev, Moshe Deutsch, Benjamin M. Ocko, Mati Meron, Binhua Lin, Peter S. Pershan; "Surface Crystallization in a Liquid AuSi Alloy".

Measurements were carried out at the <u>Advanced Photon Source</u> (Argonne National Laboratory), beamline 15-ID-C (<u>ChemMatCARS</u>), and at the <u>National Synchrotron Light Source</u> (Brookhaven National Laboratory), beamline X22B. Both Argonne National Laboratory and Brookhaven National Laboratory are funded by the U.S. Department of Energy's Office of Science.

The contents of all materials on lightsources.org are the sole responsibility of the authors of the materials and/or the facilities or institutions under whose auspices the materials were produced. -lightsources.org]

 Tags: <u>APS - Advanced Photon Source</u>
 Chemistry and Materials Science
 NSLS - National

 Synchrotron Light Source
 Nanoscience
 Nanoscience
 Nanoscience



Copyright 2006 | Disclaimer